

isc N-Channel MOSFET Transistor

IRFB31N20D, IIRFB31N20D

• FEATURES

- Static drain-source on-resistance:
 R_Ds(on) ≤82mΩ
- Enhancement mode
- · Fast Switching Speed
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

High Frequency DC-DC converters

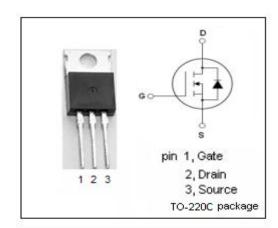
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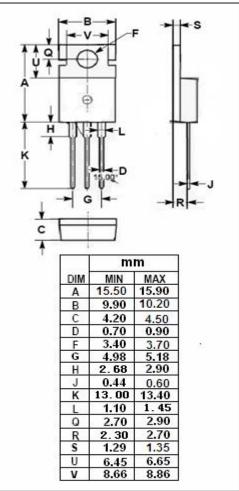
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	200	V	
V _{GS}	Gate-Source Voltage	±30	V	
I _D	Drain Current-Continuous	31	А	
I _{DM}	Drain Current-Single Pulsed	124	А	
P _D	Total Dissipation @Tc=25°C	200	W	
Tj	Max. Operating Junction Temperature 175		°C	
T _{stg}	Storage Temperature	-55~175	°C	

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	0.75	°C/W
Rth(ch-a)	Rth(ch-a) Channel-to-ambient thermal resistance		°C/W







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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D =250 μ A	200			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} ; ID =250 μ A	3		5.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D =18A			82	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±30V			±0.1	μА
I _{DSS}	Drain-Source Leakage Current	V _{DS} =200V; V _{GS} = 0V			25	μА
V _{SD}	Diode forward voltage	I _F =18A; V _{GS} = 0V			1.3	V

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